



Features

- ◊ Low power loss, high efficiency
- ◊ High current capability, Low forward voltage drop.
- ◊ Plastic material used carries Underwriters Laboratory Classification 94V-0
- ◊ High surge current capability
- ◊ Qualified as per AEC-Q101
- ◊ Guard-ring for transient protection
- ◊ For use in low voltage, high frequency inverter, freewheeling, and polarity protection application
- ◊ High temperature soldering guaranteed: 260°C/10S/.375"(9.5mm) lead lengths 5 lbs tension

Mechanical Data

- ◊ Case: ITO-220AB
- ◊ Terminals: Pure tin plated leads, solderable per MIL-STD-202, Method 208 guaranteed
- ◊ Polarity: As marked
- ◊ Weight: 1.7 grams
- ◊ Mounting Torque: 5 in-lbs. max.
- ◊ Mounting position: Any

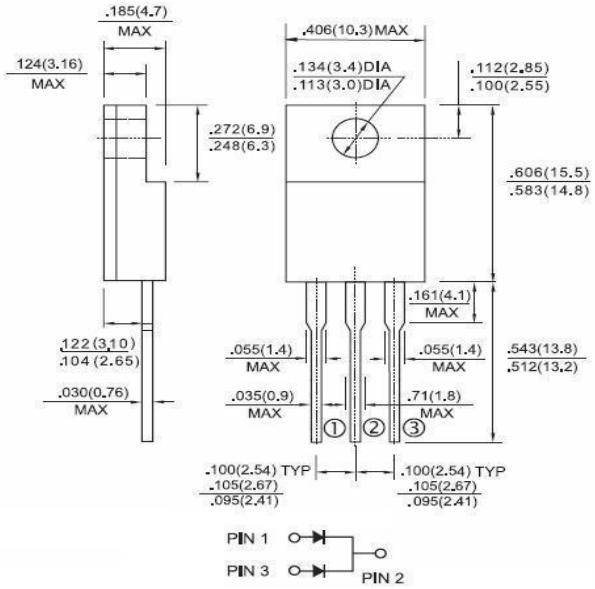
Maximum Ratings and Electrical Characteristics

Rating at 25 °C ambient temperature unless otherwise specified.

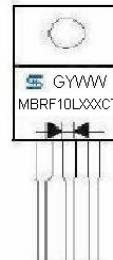
Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

MBRF10L100CT Low VF Isolated 10.0Amp Schottky Barrier Rectifier ITO-220AB



Dimensions in inches and (millimeters)



Marking Diagram

MBRF10LXXXCT = Specific Device Code
 G = Green Compound
 Y = Year Code
 WW = Work Week Code

Parameter	Symbol	MBRF10L100CT		Unit
Maximum Repetitive Peak Reverse Voltage	V _{RRM}	100		V
Maximum RMS Voltage	V _{RMS}	70		V
Maximum DC blocking voltage	V _{DC}	100		V
Maximum Average Forward Rectified Current	I _{F(AV)}	10		A
Peak Repetitive Forward Current (Rated VR, Square Wave, 20KHz)	I _{F(RMS)}	10		A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load	I _{FSM}	120		A
Peak Repetitive Reverse Surge Current (Note 1)	I _{RRM}	1		A
Maximum Instantaneous Forward Voltage (Pulse test: tp=300us, δ < 1%) @ 5A / Ta=25°C @ 5A / Ta=125°C @ 10A / Ta=25°C @ 10A / Ta=125°C	V _F	TYP. 0.73 0.59 0.82 0.66	Max. 0.76 0.65 0.85 0.71	V
Maximum Reverse Current (Pulse test: tp=300us, δ < 1%) Ta=25 °C Ta=125 °C	I _R	TYP. 0.3 0.5	Max. 20 15	uA mA
Voltage rate of change (rated V _R)	dV/dt	10,000		V/uS
Typical Junction Capacitance (Note 2)	C _j	185		pF
Typical Thermal Resistance (Note 3)	R _{θJC}	5.5		°C/W
Operating Temperature Range	T _J	-55 to + 150		°C
Storage Temperature Range	T _{STG}	-55 to + 150		°C

Note1: 2.0uS Pulse Width, F=1.0KHz, Continues 10 cycles

Note2: Measured at 1 MHz and Applied Reverse Voltage of 4.0 V D.C.

Note3: Mount on Heatsink Size of 4" x 6" x 0.25" Al-Plate

RATINGS AND CHARACTERISTIC CURVES (MBRF10L100CT)

Fig.1 Maximum Forward Current Derating Curve

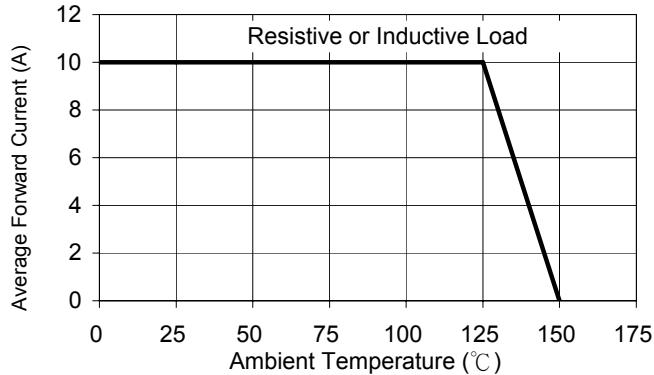


Fig. 2 Maximum Forward Surge Current

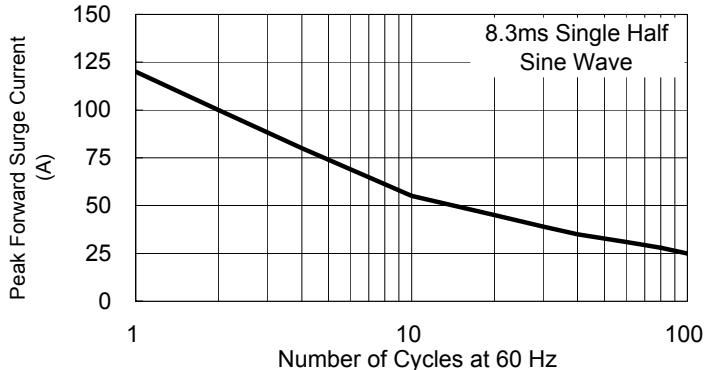


Fig. 3 Typical Forward Characteristics

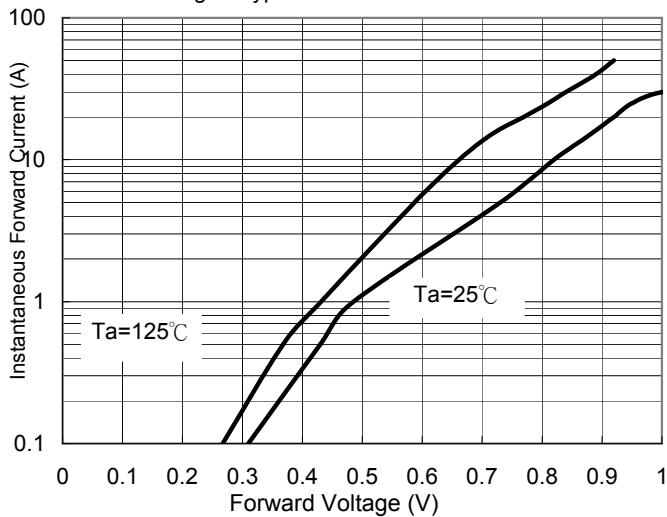


Fig. 4 Typical Reverse Characteristics

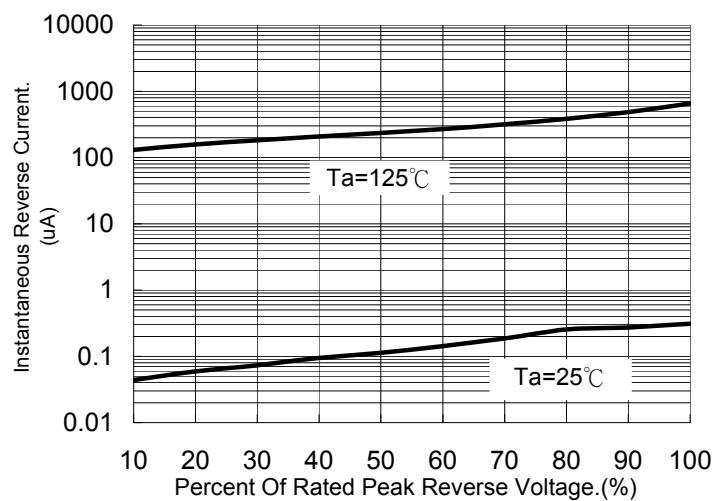


Fig. 5 Typical Junction Capacitance

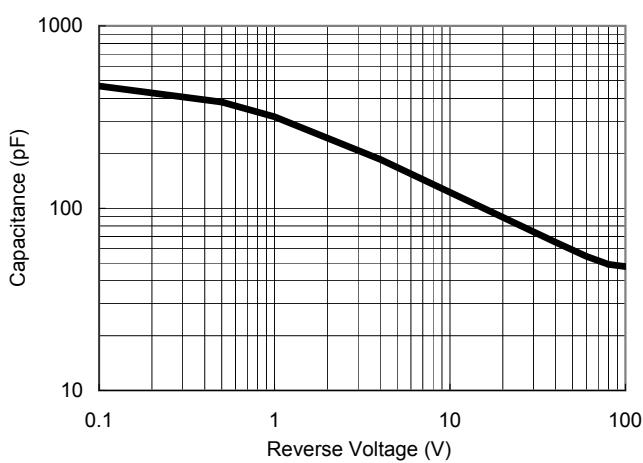


Fig. 6 Typical Transient Thermal Impedance

